				Group Art Unit	2814	
ventor(s):	UEMURA et al		JAN 2 7 1999	Examiner.	Wille, D	
opln. No.:	08	866,129	0000	Atty. Dkt. PMS	238641	

Serial No. + GROUP 210() Series Code ↑ Filed[®] May 30, 1997

METHODS AND DEVICES RELATED TO ELECTRODE PADS

FOR P-TYPE GROUP III NITRIDE COMPOUNDOTS

Asst. Commissioner of Patents Washington, D.C. 20231

Sir

Title:

F97-121-US Client Ref M# (Our Deposit Account No. 03-3975) 238641 (Our Order No.

31317 January 19, 1999 Date:

This is a reply/amendment/letter in the above-identified application and includes the herewith attachment of same date and subject which is incorporated hereinto by reference and the signature below is treated as the signature to the attachment in absence of a signature thereto.

DMENT/LETTER

FEE REQUIREMENTS FOR CLAIMS AS AMENDED

"Small Entity" statement(s) filed							
previously herewith (No.)	Claims remaining after amendment	Highest nu previously p		Present Extra	Large/Small Entity	Additional Fee	Fee Code
2. Total Effective Claims	21	**minus	20	1	x \$18/\$9 =	+ 18	103/203
3. Independent Claims	3	***minus	3	0	x \$78/\$39 =	+ 0	102/202
4. If amendment enters proper mult time (leave blank if this is a reissue	+ 0	104/204					
5. Original due Date: November 19, 1998 NONE							,
6. Petition is hereby made to exte due date to cover the date this resp for which the requisite fee is attached	(1 mo) (2 mos) (3 mos)		\$110/\$55 = \$380/\$190 = \$870/\$435 =	+ 380		115/215 116/216 117/217	
7. Enter any previous extension fee							
8.	+ 380						
9. If Terminal Disclaimer attached	+0	148/248					
10. If IDS attached requires Official or if Rule 97(d) Petition	+ 0	126 122					
11. After-Final Request Fee per rule	+0	146/246					
12. No. of additional inventions for	+0	149/249					
13. Petition fee for	+						
14	\$398						
		_					-

15. *If the entry in this space is less than entry in next space, the "Present Extra" result is "0"

16 **If the "Highest number previously paid for" in this space is less than 20, write "20" in this space

17. ***If the "Highest number previously paid for" in this space is less than 3, write "3" in this space.

CHARGE STATEMENT: The Commissioner is hereby authorized to charge any fee specifically authorized hereafter, or any missing or insufficient fee(s) filed, or asserted to be filed, or which should have been filed herewith or concerning any paper filed hereafter, and which may be required under Rules 16-18 (missing or insufficiencies only) now or hereafter relative to this application and the resulting Official Document under Rule 20. or credit any overpayment, to our Accounting Order Nos, shown in the heading hereof, for which purpose a duplicate copy of this sheet is attached.

This CHARGE STATEMENT does not authorize charge of the issue fee until/unless an issue fee transmittal sheet is filed.

Query: Is appeal deadline now? If so, file Notice of Appeals separately.

Pillsbury Madison & Sutro LLP Intellectual Property Group

1100 New York Avenue, N.W. By Atty: Peter W. Gowdey Ninth Floor East Tower Washington, D.C. 20005-3918

Sig:

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(202) 822-0944 Fax:

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Atty/Sec: PWG/RYM:sac NOTE: File this cover sheet in duplicate with PTO receipt (PAT-103A) and attachments

00000163 08866123 01/25/1999 REMALAT

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01 FC:103 02 FC:116

18.00 BP 380.00 OP

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

UEMURA et al

Appln. No.: 08/866,129

Filed: May 30, 1997

Atty. Dkt. No.: 238641

Group Art Unit: 2814

RFCEIVED Examiner: D. Willie

JAN 2 7 1999

METHODS AND DEVICES RELATED TO For: ELECTRODE PADS FOR P-TYPE GROUP 2100

JAN 1 9 199**9**

NITRIDE COMPOUND SEMICONDUCTORS

January 19, 1999

AMENDMENT/RESPONSE

Hon. Commissioner of Patents and Trademarks Washington, D.C. 20231

Dear Sir:

In response to the Office Action dated August 19, 1998, please enter the following amendments and consider the following remarks.

IN THE CLAIMS:

Kindly add the following new claims.

(New) An electrode pad according to claim 6, wherein --20.

materials of said second electrode layer do not permeate into said first electrode layer right under said\electrode pad, which enables the interface between said electrode layer and said semiconductor right under said electrode pad to have a large resistivity and not have electric current pass therethrough.

21. (New) A light-emitting semiconductor device of a Group III nitride compound semiconductor with p-type conduction according to claim 12, wherein

materials of said second electrode layer do not permeate into said first electrode layer right under said electrode pad, which enables the interface between said electrode